



Central Plate
Electronics Co., Ltd.

SRF4030CT THRU SRF40200CT

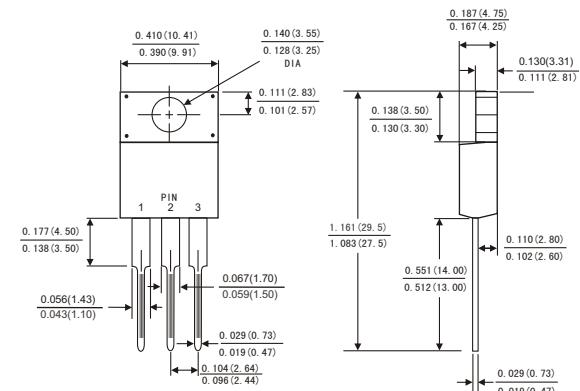
SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 30 to 200 Volts
Forward Current - 40.0 Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage ,high frequency inverters,
free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds,
0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and
WEEE 2002/96/EC

MECHANICAL DATA

- Case: JEDEC ITO-220AB molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SRF 4030CT	SRF 4035CT	SRF 4040CT	SRF 4045CT	SRF 4050CT	SRF 4060CT	SRF 40100CT	SRF 40150CT	SRF 40200CT	Units
Maximum repetitive peak reverse voltage	V _{RRM}	30	35	40	45	50	60	100	150	200	Volts
Maximum RMS voltage	V _{RMS}	21	25	28	32	35	42	70	105	140	Volts
Maximum DC blocking voltage	V _{DC}	30	35	40	45	50	60	100	150	200	Volts
Maximum average forward rectified current(see Fig.1)	Per leg Total device	I _(AV)					20.0	40.0			Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}						300.0				Amps
Maximum instantaneous forward voltage at 40.0 A	V _F		0.60			0.75		0.85	0.95		Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T _c =25°C T _c =125°C	I _R				0.2					mA
			30				50				
Typical thermal resistance (Note 2)	R _{θJC}					3.0					°C/W
Operating junction temperature range	T _J					-65 to +150					°C
Storage temperature range	T _{STG}					-65 to +150					°C

Notes: 1.Pulse test: 300 μ s pulse width,1% duty cycle

2.Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SRF40 30CT THRU SRF40 200CT

FIG.1-FORWARD CURRENT DERATING CURVE

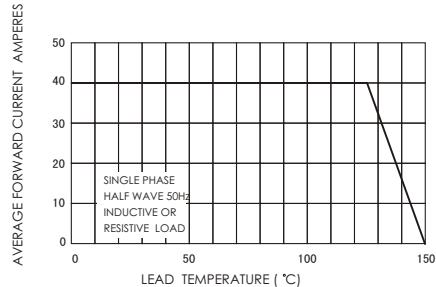


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

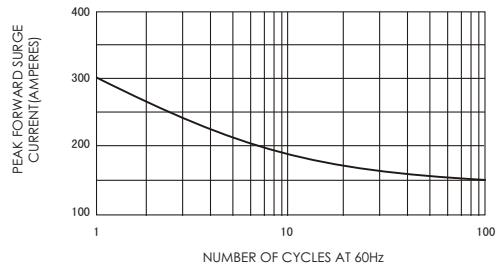


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

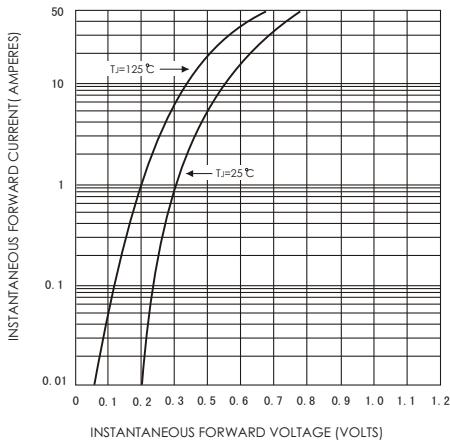


FIG.4-TYPICAL REVERSE CHARACTERISTICS

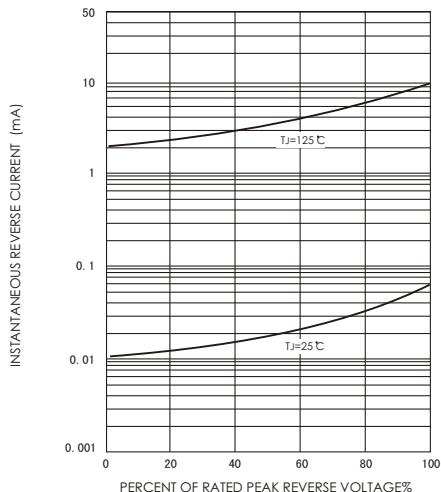


FIG.5-TYPICAL JUNCTION CAPACITANCE

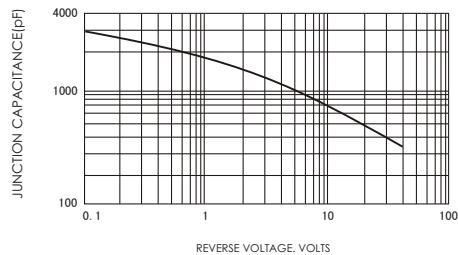


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

